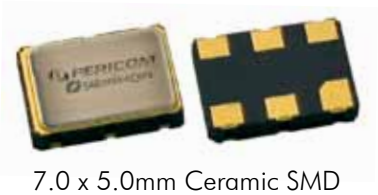
PERICOM
SaRonix-eCera

ASSP VCXO

Application Specific Voltage Controlled Crystal Oscillator 7.0 x 5.0mm

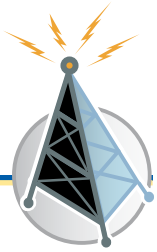
3.3V CMOS 61.44MHz Base Station VCXO

FRBST1061



7.0 x 5.0mm Ceramic SMD

ASSP VCXO™ for Base Station



Product Features

- Very low Pk to Pk jitter - 40ps Max
- Low supply current - 10mA Max
- Low power standby mode
- RoHS Compliant

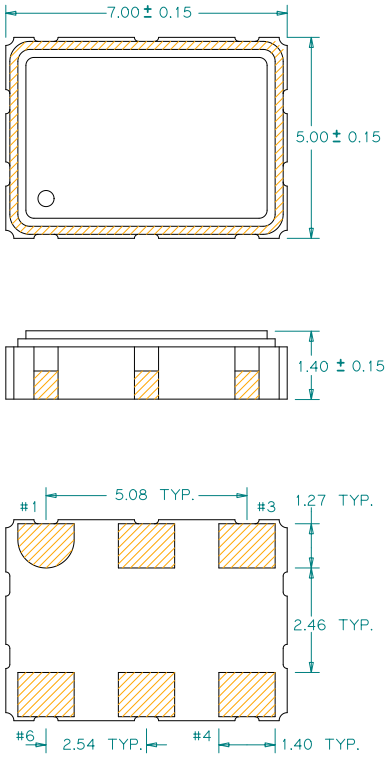
Product Description

This is an enhanced 3.3V, 61.44MHz with superb jitter and low operating current for providing clock references in base station applications.

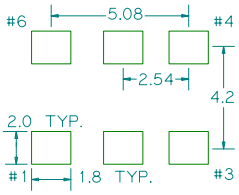
Applications

- Base Station

Package: (Scale: none, Dimensions are in mm)



Recommended Land Pattern:



Pin Functions:

Pin	Function
1	Control Voltage
2	Enable/Disable
3	Ground
4	Output
5	N/C
6	V_{DD}

*Extended high frequency power decoupling is recommended (see test circuit for minimum recommendation). To ensure optimal performance, do not route RF traces beneath the package.

Part Ordering Information:

FRBST1061

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Application Specific Voltage Controlled Crystal Oscillator 7.0 x 5.0mm

Electrical Performance

Parameter	Min.	Typ.	Max.	Units	Notes
Output Frequency		61.440		MHz	
Supply Voltage V_{DD}	3.135	3.3	3.465	V	
Supply Current, Output Enabled			10	mA	
Supply Current, Output Disabled			3	mA	
Frequency Stability			±50	ppm	See Note 1 below
Operating Temperature Range	-40		+85	°C	
Output Logic 0, V_{OL}			10% V_{DD}	V	
Output Logic 1, V_{OH}	90% V_{DD}			V	
Output Load			15	pF	
Duty Cycle	45		55	%	Measured 50% V_{DD}
Rise and Fall Time			4	ns	Measured 20/80% of waveform
Jitter, Phase, RMS(1-σ)			1	ps	12kHz~20MHz Frequency Band
Jitter, Peak to Peak (Pk-Pk)			40	ps	100.000 Random Periods
Phase Noise		-55		dBc/Hz	At 10Hz offset
Phase Noise		-90		dBc/Hz	At 100Hz offset
Phase Noise		-122		dBc/Hz	At 1kHz offset
Phase Noise		-134		dBc/Hz	At 10kHz offset
Phase Noise		-150		dBc/Hz	At 100kHz offset
Phase Noise		-155		dBc/Hz	At 1MHz offset

Notes:
1. Stability includes all combinations of operating temperature, load changes, rated input (supply) voltage changes, initial calibration tolerance (25°C), aging (10 years at +40°C average effective ambient temperature), shock and vibration.
2. For specifications othere than those listed, please contact sales.

Voltage Control Function

Parameter	Min.	Typ.	Max.	Units	Notes
Absolute Pull Range (APR)	±50			ppm	See 1 below
Control Voltage Range	0.3		3.0	V	As rated
Center Control Voltage		1.65		V	For RMT Nominal Frequency
Monotonic Linearity			10	%	Positive Transfer Slope
Input Impedance	5000			kΩ	Control Voltage Pin

Notes:
1. APR is relative to the nominal output frequency; APR is inclusive of frequency deviation due to stability.

Output Enable / Disable Function

Parameter	Min.	Typ.	Max.	Units	Notes
Input Voltage (pin 2), Output Enable	3.0			V	or open
Input Voltage (pin 2), Output Disable (low power standby)			0.3	V	Output is Hi-Z
Internal Pullup Resistance		20		kΩ	
Output Disable Delay			100	ns	
Output Enable Delay			100	ns	

Absolute Maximum Ratings

Parameter	Min.	Typ.	Max.	Units	Notes
Storage Temperature	-55		+125	°C	

For the latest product information visit: http://www.pericom.com/products/crystals-and-crystal-oscillators/assp-xo/?part=FRBST1061
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